

HIGH SURGE TVS DIODE FOR LATCH-UP PROTECTION

Features

- 2800 Watts Peak Pulse Power per Line (tp=8/20µs)
- Protects One Unidirectional Line
- Low Clamping Voltage
- Working Voltages: 24V
- Low Leakage Current
- IEC61000-4-2 (ESD) ±30kV (air), ±30kV (contact)
- IEC61000-4-4 (EFT) 40A (5/50ηs)
- IEC61000-4-5 (LIGHTING) 58A (8/20 μs)

Applications

- Cellular Phones
- ADSL and VDSL
- Parallel & Serial Port Protection
- Personal Digital Assistant (PDA)
- Microcontroller Input Protection
- Charager Protection

Mechanical Characteristics

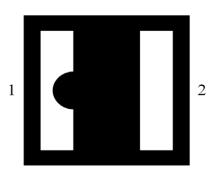
• DFN2020SP2 Package

• Molding Compound Flammability Rating: UL 94V-O

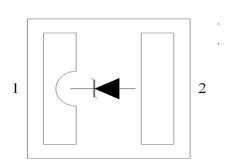
• Quantity Per Reel: 3,000pcs

Reel Size : 7 inchLead Finish : Lead Free

Dimensions DFN2020SP2



Pin Configuration



Absolute Maximum Ratings(Tamb=25°C unless otherwise specified)

Parameter	Symbol	Value	Unit	
Peak Pulse Power (8/20µs)	Ррр	2800	W	
ESD per IEC 61000-4-2 (Air)	Vesd	±30	Kv	
ESD per IEC 61000-4-2 (Contact)	VESD	±30		
Operating Temperature Range	TJ	-55 to +125	$^{\circ}$	
Storage Temperature Range	Тѕтл	-55 to +150	$^{\circ}$	



Electrical Characteristics (TA=25°C unless otherwise specified)

Part Number	Device Marking	V _{RWM} (V)	V _{BR} (V)	I _⊤ (mA)	Vc @1A	(Max)	(@A)	I _R μΑ (Max)	C (Pf) (Typ.)
SMDA24P2	SMDA24SP2	24	26.7	1	29.5	48.5	58	1	-

TYPIC CHARACTERISTICS

Figure 1. $8 \times 20 \mu$ s Waveform

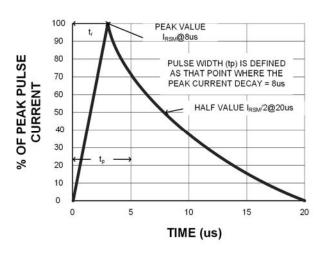


Figure 2. Power Derating Curve

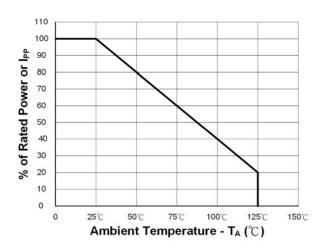
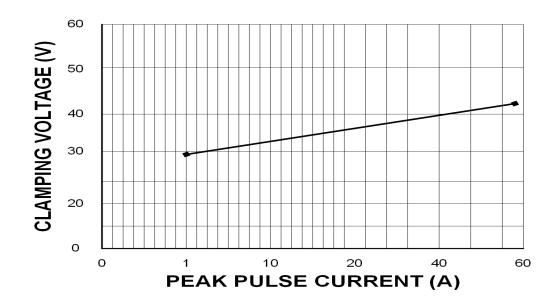


Figure 3. Clamping Voltage vs. Peak Pulse Current (tp=8/20us)



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TYPIC CHARACTERISTICS



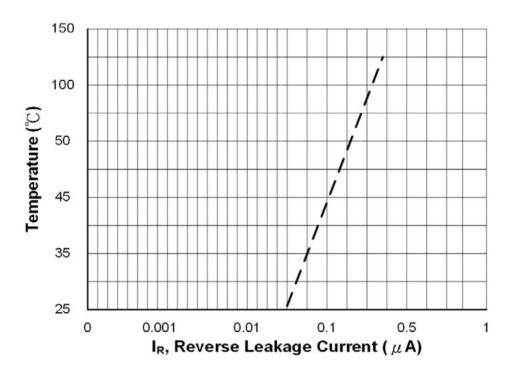
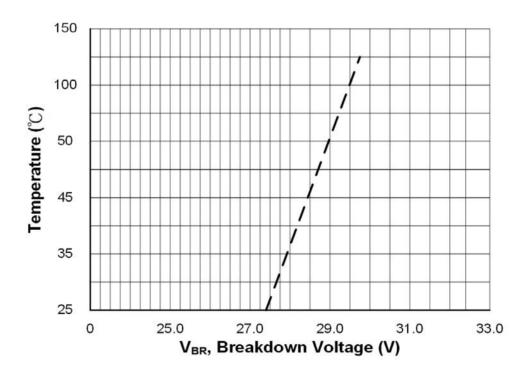


Figure 5. Typic Breakdown Voltage vs. Temperature

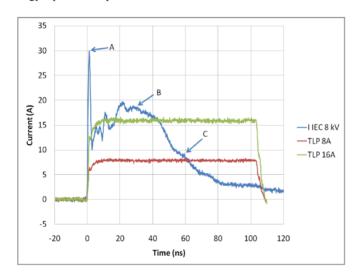


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Transmission Line Pulse (TLP)

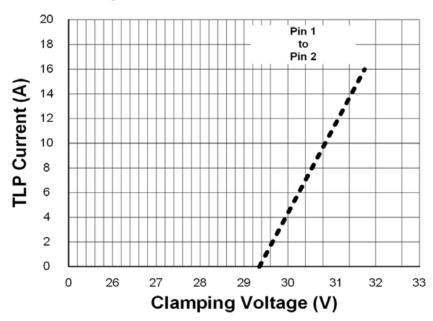
Transmission Line Pulse (TLP) is a measurement technique used in the Electrostatic Discharge (ESD) arena to characterize performance attributes of devices under ESD stresses. TLP is able to obtain current versus voltage (I–V) curves in which each data point is obtained with a 100 ns long pulse, with currents up to 40 A. TLP was first used in the ESD field to study human body model (HBM) in integrated circuits, but it is an equally valid tool in the field of system level ESD. The applicability of TLP to system level ESD is illustrated in Figure 1, which compares an 8 kV IEC 61000–4–2 current waveform with TLP current pulses of 8 and 16 A. The current levels and time duration for the pulses are similar and the initial rise time for the TLP pulse is comparable to the rise time of the IEC 61000–4–2's initial current spike. This application note will give a basic introduction to TLP measurements and explain the datasheet parameters extracted from TLP for SDI Technology's protection products.



Comparison of a Current Waveform of IEC 61000-4-2 with TLP Pulses at 8 and 16 A.

The IEC 61000–4–2 ESD waveforms is true to the Standard and is shown here as captured on an oscilloscope. The points A, B, and C show the points on the waveforms specified in IEC 61000–4–2.

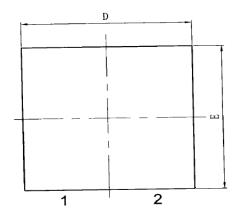
Figure 6. TLP Characteristic



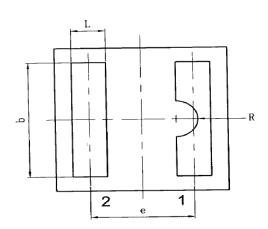
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DFN2020SP2 PACKAGE OUTLINE & DIMENSIONS

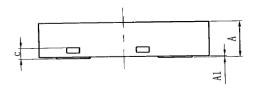






TOP VIEW

BOTTOM VIEW



SYMBOL	MILLIMETER			
STMBOL	MIN	NOM	MAX	
A	0. 45	0.50	0. 55	
A1		0. 02	0. 05	
ь	1. 55	1. 60	1. 65	
С	0. 10	0. 15	0. 20	
D	1. 90	2.00	2. 10	
е	1. 20BSC			
Е	1. 90	2. 00	2. 10	
L	0. 35	0. 40	0. 45	
R	0. 20	0. 25	0. 30	
载体尺寸 (Mil)	43X71/22X71			

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